# 40 Watt Peak Power Zener Transient Voltage Suppressors

# SC-70 Dual Common Cathode Zeners for ESD Protection

These dual monolithic silicon zener diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. Their dual junction common cathode design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

#### **Specification Features:**

- SC-70 Package Allows Either Two Separate Unidirectional Configurations or a Single Bidirectional Configuration
- Working Peak Reverse Voltage Range 22 V
- Standard Zener Breakdown Voltage 27 V
- Peak Power 40 W @ 1.0 ms (Bidirectional), per Figure 4 Waveform
- ESD Rating of Class N (exceeding 16 kV) per the Human Body Model
- Low Leakage < 100 nA
- Flammability Rating: UL 94 V-O
- This is a Pb-Free Device

#### **Mechanical Characteristics:**

**CASE:** Void-free, transfer-molded, thermosetting plastic case **FINISH:** Corrosion resistant finish, easily solderable

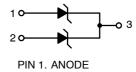
# MAXIMUM CASE TEMPERATURE FOR SOLDERING PURPOSES:

260°C for 10 Seconds

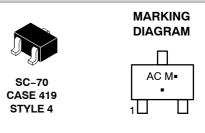


# **ON Semiconductor®**

http://onsemi.com







AC = Specific Device Code M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>			
MMBZ27VCWT1G	SC–70 (Pb–Free)	3000/Tape & Reel			

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation @ 1.0 ms (Note 1) @ $T_L \le 25^{\circ}C$	P <sub>pk</sub>	40	Watts
Total Power Dissipation on FR–5 Board (Note 2) @ T <sub>A</sub> = 25°C Derate above 25°C	P <sub>D</sub>	200 1.6	mW mW/°C
Thermal Resistance Junction-to-Ambient	$R_{\thetaJA}$	618	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Nonrepetitive current pulse per Figure 4 and derate above  $T_A = 25^{\circ}C$  per Figure 5.

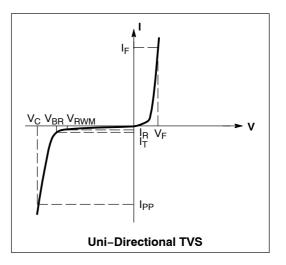
2.  $FR-5 = 1.0 \times 0.75 \times 0.62$  in.

#### **ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub> = 25°C unless otherwise noted)

UNIDIRECTIONAL (Circuit tied to Pins 1 and 3 or 2 and 3)

Symbol	Parameter					
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current					
V <sub>C</sub>	Clamping Voltage @ IPP					
V <sub>RWM</sub>	Working Peak Reverse Voltage					
I <sub>R</sub>	Maximum Reverse Leakage Current @ V <sub>RWM</sub>					
V <sub>BR</sub>	Breakdown Voltage @ I <sub>T</sub>					
Ι <sub>Τ</sub>	Test Current					
V <sub>BR</sub>	Maximum Temperature Coefficient of $V_{BR}$					
١ <sub>F</sub>	Forward Current					
V <sub>F</sub>	Forward Voltage @ I <sub>F</sub>					



#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted) **UNIDIRECTIONAL** (Circuit tied to Pins 1 and 3 or Pins 2 and 3)

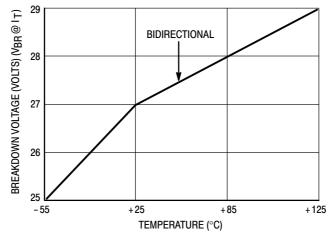
#### (V<sub>F</sub> = 1.1 V Max @ I<sub>F</sub> = 200 mA)

				Breakdown Voltage				V <sub>C</sub> @ I <sub>PF</sub>		
	Device	V <sub>RWM</sub>	I <sub>R</sub> @ V <sub>RWM</sub>	V <sub>BR</sub> (Note 3) (V)			@ I <sub>T</sub>	v <sub>c</sub>	I <sub>PP</sub>	V <sub>BR</sub>
Device	Marking	Volts	nA	Min	Nom	Max	mA	v	Α	mV/°C
MMBZ27VCWT1G	AC	22	50	25.65	27	28.35	1.0	38	1.0	26

3. V<sub>BR</sub> measured at pulse test current I<sub>T</sub> at an ambient temperature of 25°C.

4. Surge current waveform per Figure 4 and derate per Figure 5

#### **TYPICAL CHARACTERISTICS**





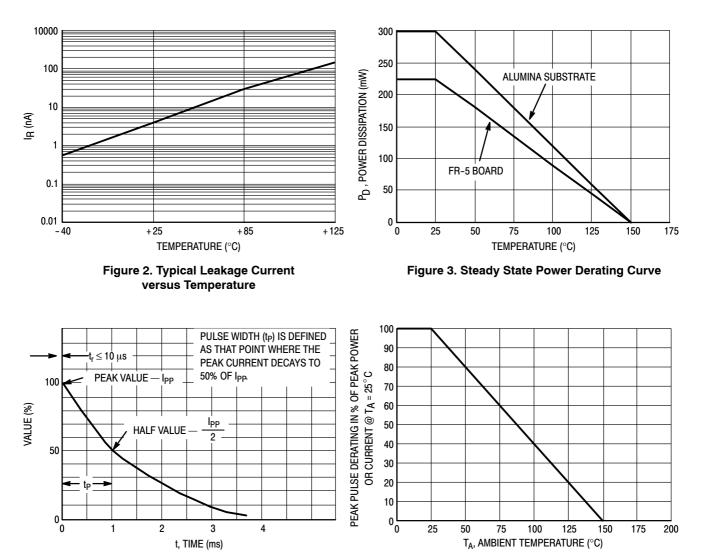
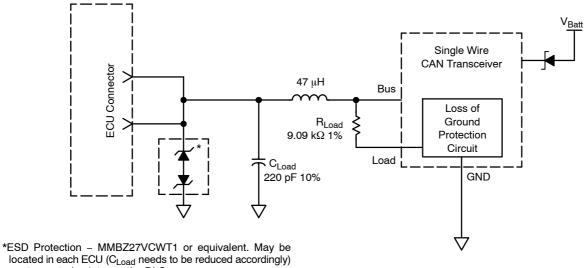




Figure 5. Pulse Derating Curve

#### **TYPICAL APPLICATIONS**



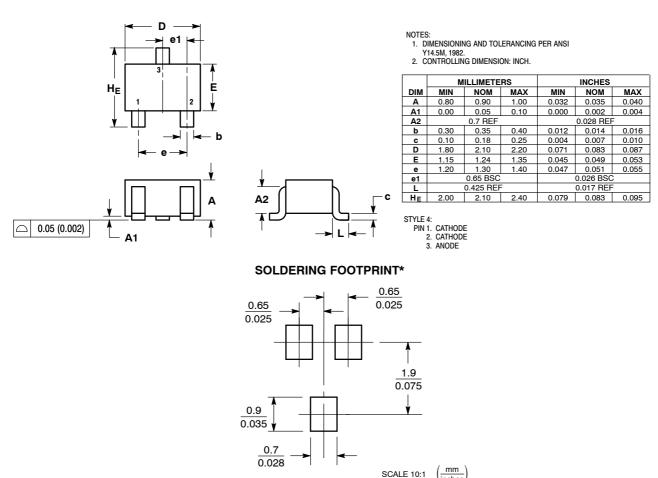
or at a central point near the DLC.

Figure 6. Single Wire CAN Network

Figure is the recommended solution for transient EMI/ESD protection. This circuit is shown in the Society of Automotive Engineers February, 2000 J2411 "Single Wire CAN Network for Vehicle Applications" specification (Figure 6, page 11). Note: the dual common anode zener configuration shown above is electrically equivalent to a dual common cathode zener configuration.

#### PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 **ISSUE M** 



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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